NCE3080I

NCE N-Channel Enhancement Mode Power MOSFET

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Description

The NCE3080I uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =80A

 $R_{DS(ON)}$ <6.5m Ω @ V_{GS} =10V

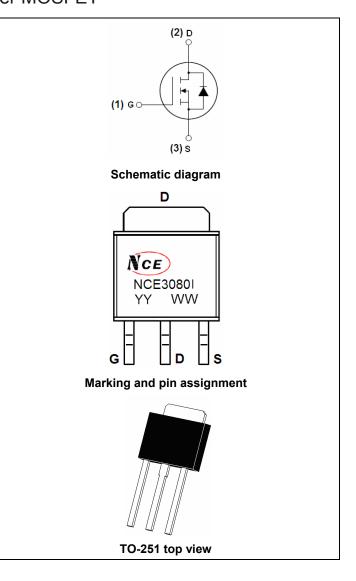
 $R_{DS(ON)}$ < 10m Ω @ V_{GS} =5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3080I	NCE3080I	TO-251	-	-	-

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	±20	V	
Drain Current-Continuous	I _D	80	А	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	50	А	
Pulsed Drain Current	I _{DM}	170	А	
Maximum Power Dissipation	P _D	83	W	
Derating factor		0.56	W/℃	
Single pulse avalanche energy (Note 5)	E _{AS}	150	mJ	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\mathbb{C}$	



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Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	1.8	°C/W
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol Condition		Min	Тур	Max	Unit	
Off Characteristics	<u> </u>						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μΑ	
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA	
On Characteristics (Note 3)	<u> </u>		•				
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.5	3	V	
Paris On the Original Paris Inches	R _{DS(ON)}	V _{GS} =10V, I _D =30A	-	5.5	6.5		
Drain-Source On-State Resistance		V _{GS} =5V, I _D =24A -		7.5	10	mΩ	
Forward Transconductance	g FS	V _{DS} =5V,I _D =24A	20	-	-	S	
Dynamic Characteristics (Note4)			·	ı			
Input Capacitance	C _{lss}	1/ 45)/)/ 0)/	-	2330	-	PF	
Output Capacitance	C _{oss}	V_{DS} =15V, V_{GS} =0V,	-	460	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	230	-	PF	
Switching Characteristics (Note 4)	<u> </u>						
Turn-on Delay Time	t _{d(on)}		-	20	-	nS	
Turn-on Rise Time	t _r	V_{DD} =10 V , I_{D} =30 A	-	15	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =2.7 Ω	-	60	-	nS	
Turn-Off Fall Time	t _f		-	10	-	nS	
Total Gate Charge	Qg	V 40V/ 1 20A	-	51	-	nC	
Gate-Source Charge	Q _{gs}	$V_{DS}=10V, I_{D}=30A,$	-	14	-	nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	11	-	nC	
Drain-Source Diode Characteristics	<u> </u>						
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =24A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	80	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 80A	-	32	50	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs(Note3)	-	12	20	nC	

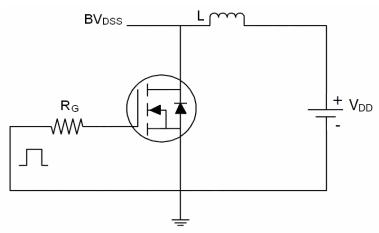
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}\!\!\mathrm{C}$,V $_{DD}$ =15V,V $_{G}$ =10V,L=1mH, Rg=25 Ω

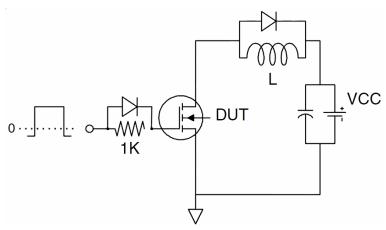
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Test Circuit

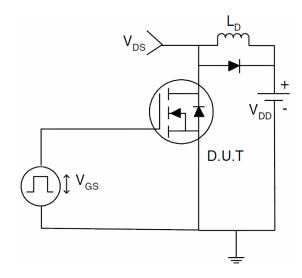
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit:



3) Switch Time Test Circuit:



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Typical Electrical and Thermal Characteristics (Curves)

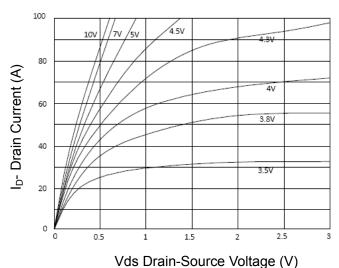


Figure 1 Output Characteristics

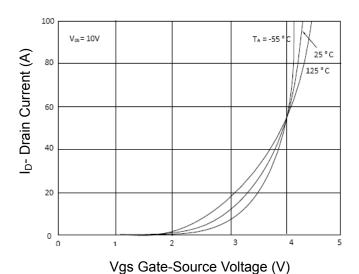


Figure 2 Transfer Characteristics

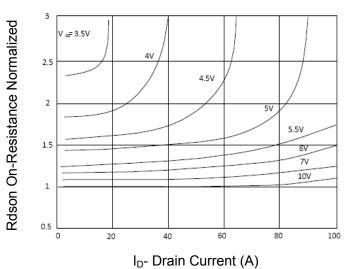


Figure 3 Rdson- Drain Current

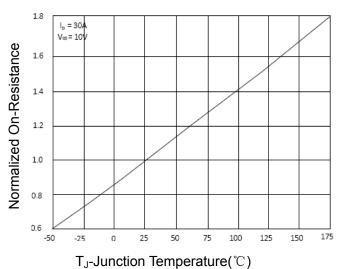


Figure 4 Rdson-Junction Temperature

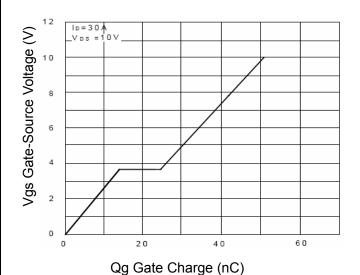


Figure 5 Gate Charge

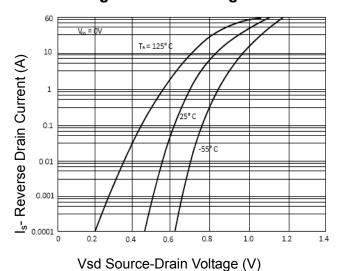
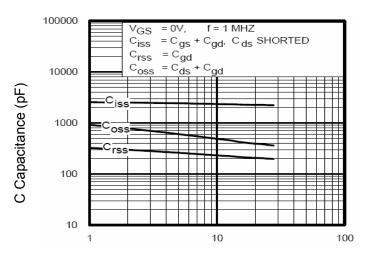


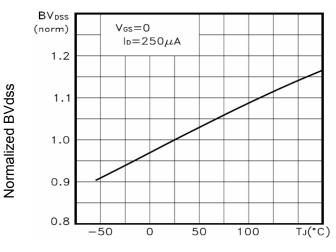
Figure 6 Source- Drain Diode Forward



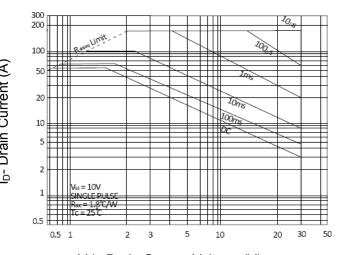


Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds

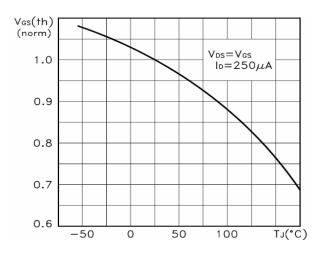


 T_J -Junction Temperature (°C) Figure 9 BV_{DSS} vs Junction Temperature



Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



 T_J -Junction Temperature($^{\circ}$ C)

Figure 10 V_{GS(th)} vs Junction Temperature

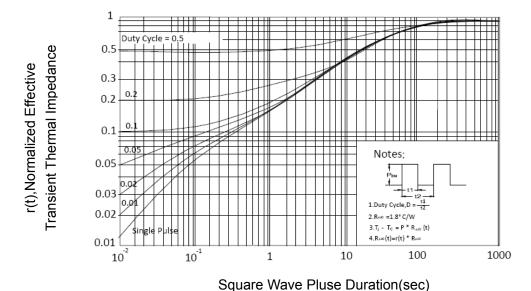
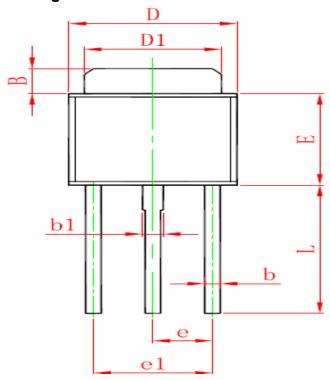


Figure 11 Normalized Maximum Transient Thermal Impedance

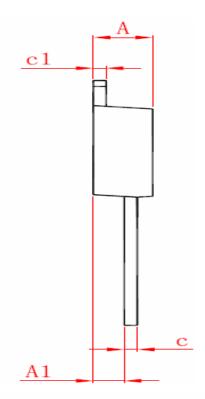
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TO-251 Package Information



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Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
Е	5.400	5.700	0.213	0.224	
е	2.300 TYP		0.091 TYP		
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	



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